

Product Quality Quick Reference Information

Quality information for product types

Quality and reliability data provided by Nexperia is intended to be a non-binding estimate of product performance only. It does not imply that any performance levels reflected in such data can be met if the product is operated outside the conditions expressly stated in the latest published datasheet for a device or in your application.

Quick reference

Information	Content
Device type	PSMN102-200Y
Orderable part number (12NC)	934061323115
Package	SOT669
Waferfab sites	Nexperia, Manchester
Assembly sites	Nexperia, Phillipines
ESD HBM	1000V - 2000V (1C)
ESD CDM	>1000V

The ESD values shown are typical representative numbers from a sample of devices tested during qualification and not guaranteed. Measurements have been conducted in accordance with JS-001-2017.

Reliability qualification information



Stress	Conditions	Duration	Quantity	Rejects
Stress	T 0500			See
Pre and Post stress electrical test	$T_{amb} = 25$ °C	N/A	All parts	below
PC	JESD22-A113	24 hours		
Preconditioning	Bake $T_{amb} = 125$ °C	168 hours	924	0
	Soak $T_{amb} = 85$ °C, RH = 85 %	3 cycles	924	U
	reflow			
HTRB	MIL-STD-750-1			
High temperature reverse bias	$T_j = T_j \text{ max}$, $V_{DS} = 80\%$ of rated	1000 hours	231	0
	Voltage M1039 Method A			
HTGB	JESD22-A108			
High temperature gate bias	$T_j = T_j \text{ max}, V_{GS} = 20V(SL), 16V$ (LL)	1000 hours	231	0
TC	JESD22-A104	500 cycles	231	0
Temperature Cycling	-55°C to 150°C	300 Cycles		
UHAST	JESD22-A118		231	0
Unbiased highly accelerated stress test	$T_{amb} = 130$ °C, RH = 85%	96 hours		
	Pressure = $+2.27$ atm			
HAST*	JESD22-A110		231	0
Highly accelerated stress test	$T_{amb} = 130$ °C, RH = 85%	96 hours		
	$V_{DS} = 80\%$ of rated voltage			
H3TRB*	JESD22-A101		231	Ŭ
Temperature Humidity bias	$T_{amb} = 85$ °C, RH = 85%	1000 hours		
	$V_{DS} = 80\%$ of rated voltage			
IOL	MIL-STD-750 method 1037	5000 cycles	231	0
Intermittent operating life	ΔTj = 80°C	sooo cy cles	231	
RSH	JESD22-A111 (SMD)	10s	30	0
Resistance to solder heat	260°C ± 5°C			
SD	IPC/ECA J-STD-002			
Solderability	Method A dip and look	3 sec dip	66	0
	No aging, solder Ta = 245°C			
	IPC/ECA J-STD-002	8 hours		
	Method B dip and look	3 sec dip		
	No aging			
	Solder Ta = 245°C		66	0
	>95% lead coverage required			
	Steam Aging: condition C			
	Steam Ta = 93°C, 8 hours			
	Solder Ta = 245°C, 3 sec dip			
	Dry Bake:	16 hours	66	0

^{*}Either HAST or HT3RB are tested for a set of devices.

Calculation of FIT and MTBF

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB) and High temperature Gate Bias (HTGB). Confidence level 60%, derated to 55°C, activation energy 0.7eV test time 168 to 1000 hours.

Technology	Quantity	Failure rate	MTBF
T3	462	2.61	3.83E+08